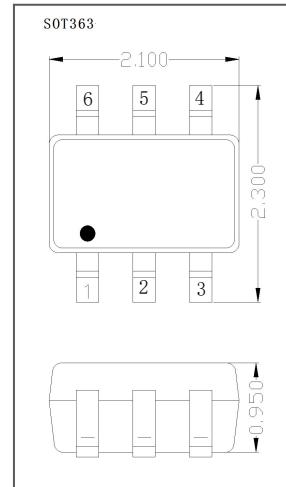
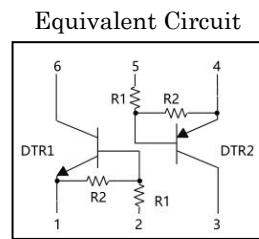


DATA SHEET

UMD9N

- ◇Epoxy meets UL 94 V-0 flammability rating
- ◇Lead Free Finish/RoHS Compliant
- ◇Mounting Possible With SOT-363 Automatic Mounting Machines
- ◇Transistor Elements Independent, Eliminating Interference

Device Marking Code	
UMD9N	D9

Maximum Ratings ($T_a = 25^\circ\text{C}$)

DTR1 NPN

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	50	V
V_{IN}	Input Voltage	-6~40	V
I_o	Output Current	70	mA
		100	mA
P_D	Power Dissipation	150	mW
T_J	Junction Temperature	150	°C
T_{stg}	Storage Temperature	-55~150	°C

DTR2 PNP

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-50	V
V_{IN}	Input Voltage	-40~6	V
I_o	Output Current	-70	mA
		-100	mA
P_D	Power Dissipation	150	mW
T_J	Junction Temperature	150	°C
T_{stg}	Storage Temperature	-55~150	°C

Electrical Characteristics @ 25 °C Unless Otherwise Specified

DTR1 NPN

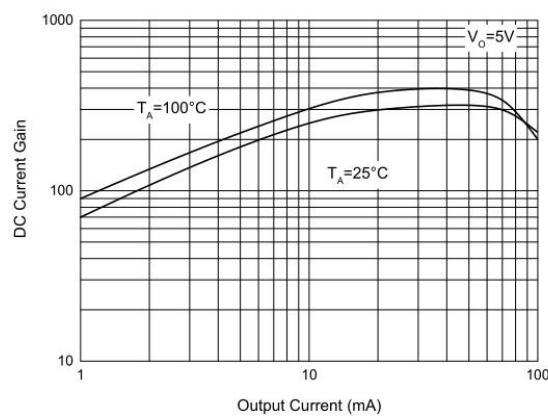
Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
$V_{I(off)}$	Input Voltage	$V_{CC}=5V, I_o=100 \mu\text{A}$	0.3			V
		$V_o=0.3V, I_o=1\text{mA}$			1.4	V
$V_{O(on)}$	Output Voltage	$I_o=5\text{mA}, I_t=0.25\text{mA}$			0.3	V

I_I	Input Current	$V_I = 5V$			0.88	mA
$I_{O(off)}$	Output Current	$V_{CC} = 50V, V_I = 0$			0.5	μA
G_I	DC Current Gain	$V_O = 5V, I_O = 5mA$	68			
R_1	Input Resistance		7	10	13	$K\Omega$
R_2/R_1	Resistance Ratio		3.7	4.7	5.7	
f_T	Transition Frequency	$V_{CE} = 10V, I_E = -5mA, f = 100MHz$		250		MHz

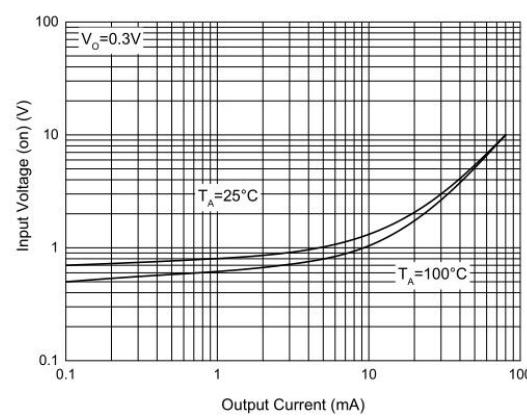
DTR2 PNP

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
$V_{I(off)}$	Input Voltage	$V_{CC} = -5V, I_O = -100 \mu A$	-0.3			V
$V_{I(on)}$		$V_O = -0.3V, I_O = -1mA$			-1.4	V
$V_{O(on)}$	Output Voltage	$I_O = -5mA, I_I = -0.25mA$			-0.3	V
I_I	Input Current	$V_I = -5V$			-0.88	mA
$I_{O(off)}$	Output Current	$V_{CC} = -50V, V_I = 0$			-0.5	μA
G_I	DC Current Gain	$V_O = -5V, I_O = -5mA$	68			
R_1	Input Resistance		7	10	13	$K\Omega$
R_2/R_1	Resistance Ratio		3.7	4.7	5.7	
f_T	Transition Frequency	$V_{CE} = -10V, I_E = 5mA, f = 100MHz$		250		MHz

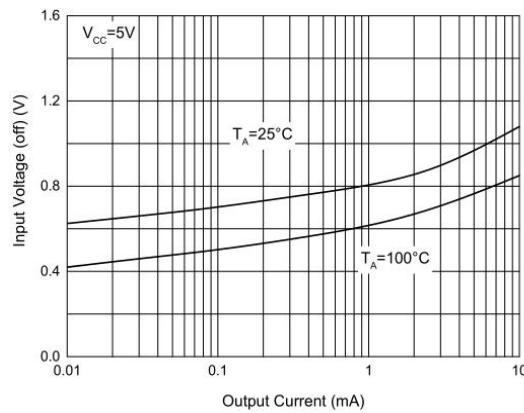
Typical Characteristics



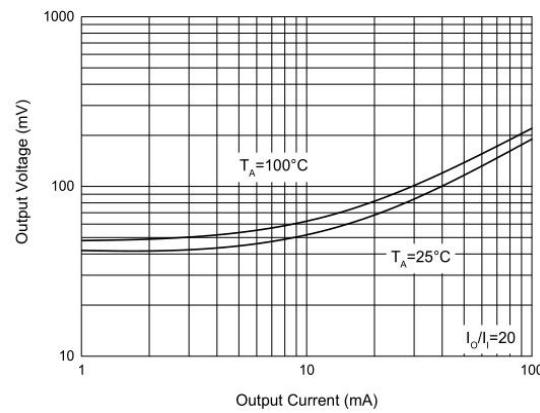
DTR1 DC Current Gain Characteristics



DTR1 Input Voltage (on) Characteristics

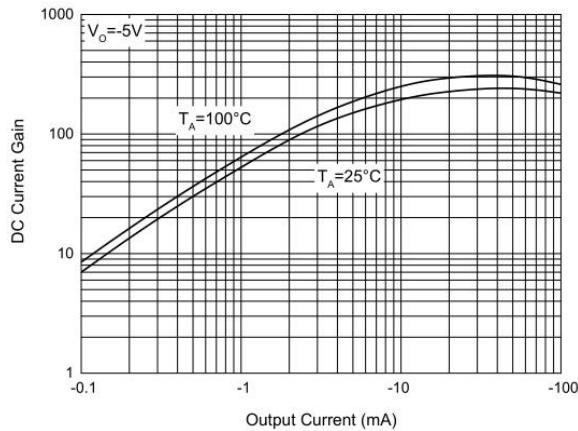


DTR1 Input Voltage (off) Characteristics

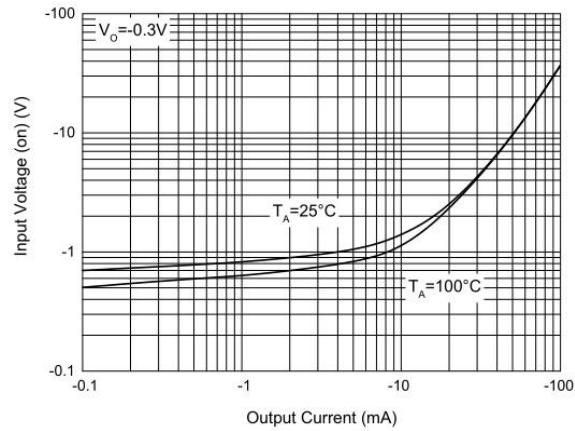


DTR1 Output Voltage Characteristics

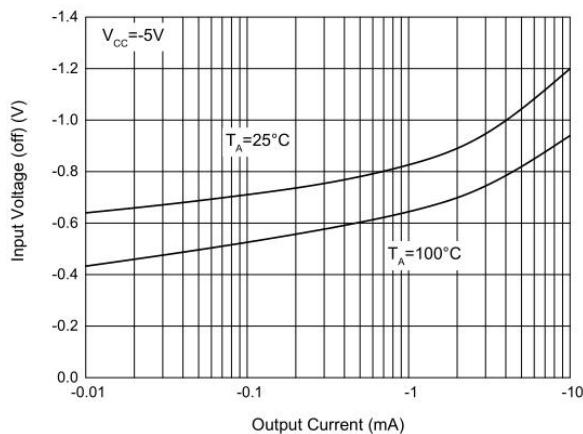
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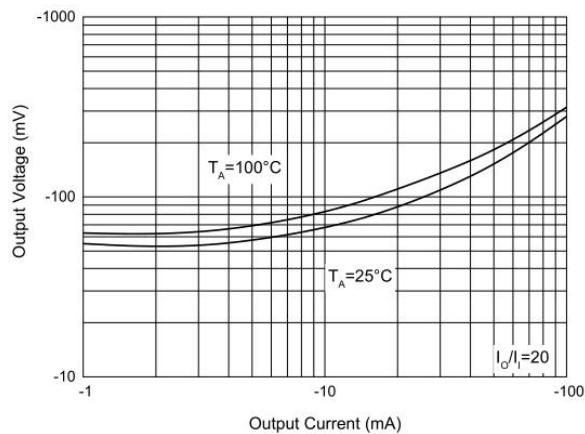
DTR2 DC Current Gain Characteristics



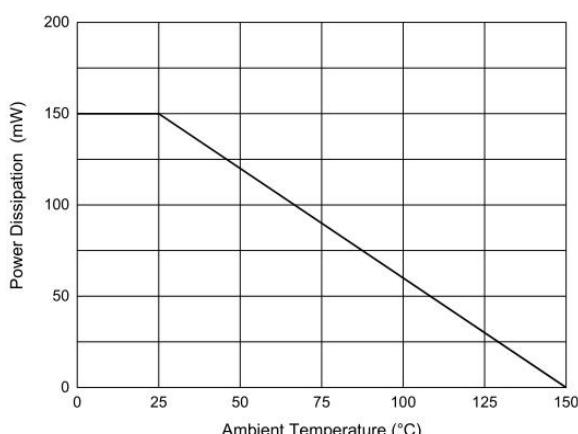
DTR2 Input Voltage (on) Characteristics



DTR2 Input Voltage (off) Characteristics



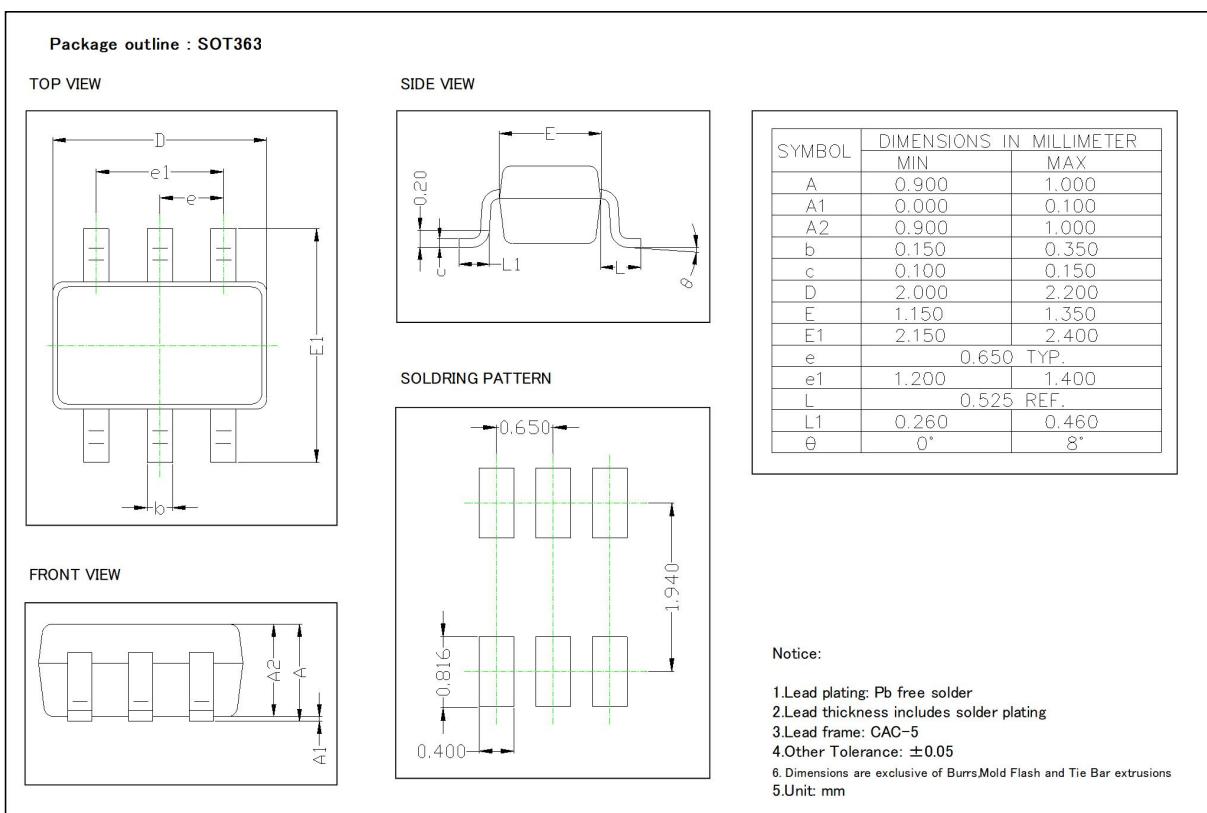
DTR2 Output Voltage Characteristics



Power Derating Curve

ORDERING INFORMATION

Device	Package	Shipping	Tape wide	Emboss pitch	Tape specification	Notes
UMD9N	SOT363	Tape & Reel 3000pcs /7" Reel	8mm	4mm	Conductive	

PACKAGE DIMENSIONS


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